NSN 5962-01-116-8676

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View Online at https://aerobasegroup.com/nsn/5962-01-116-8676

Body Length:

Between 1.065 inches and 1.105 inches

Body Width:

Between 0.380 inches and 0.393 inches

Body Height:

0.125 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Radio set, type an/arc-190

Features Provided:

Hermetically sealed and monolithic and negative outputs and positive outputs and w/buffered output and w/enable and 3-state output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

0.3 volts power source

Time Rating Per Chacteristic:

1000.00 nanoseconds propagation delay time, low to high level output and 1000.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

13499-351-8530 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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